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## TRANSPORT PROPERTIES OF $[\text{CH}(\text{FeCl}_4)_y]_x$ IN THE PRESENCE OF HYDROSTATIC PRESSURE

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**Abstract** Temperature dependence of conductivity and thermopower in region 77-300 K and pressure dependence of conductivity up to 10 kbar have been measured for  $[\text{CH}(\text{FeCl}_4)_y]_x$  for low values of  $y$  ( $0.001 < y < 0.01$ ). The results are consistent neither with ISH model nor VRH model.

### INTRODUCTION

Pauli susceptibility and Knight shift measurements<sup>1</sup> in  $[\text{CH}(\text{AsF}_6)_y]_x$  show a large increase in the number of conducting electrons when the dopand concentration reaches  $y = 0.06$ . On the other hand, the thermopower studies carried out for the same system<sup>2</sup> show that  $S$  is temperature independent only up to  $y = 0.002$  and then its behaviour is metallic-like suggesting a disappearance of the energy gap at  $y \approx 0.003$ . In addition, although the conductivity of undoped  $(\text{CH})_x$  is well described by Kivelson's intersoliton hopping mechanism (ISH)<sup>3</sup> no general theory of electrical transport for  $y > 0.001$  exists. The temperature dependences of conductivity and thermopower<sup>4</sup> seem to follow variable range hopping model (VRH)<sup>5</sup>, but only over a limited range of dopand concentrations. In order to understand the band structure changes near S-M transition and to verify both models, we have studied the influence of pressure on the transport properties of  $(\text{CH})_x$  at a low dopand concentration limit since both models predict qualitatively different behaviour of conductivity with pressure.

### EXPERIMENTAL

Trans polyacetylene, prepared using the modification of the method of Ito et al.<sup>6</sup> was used in all experiments. The dopings were

carried out in 0.05 M nitromethane solutions of  $\text{FeCl}_3$ . The measurements of electrical conductivity were performed using a standard 4-probe dc method. To achieve hydrostatic pressure conditions, helium gas was applied as pressure transmitting medium. The thermopower measurements at ambient pressure were carried out identically as described in<sup>4</sup>.

## RESULTS AND DISCUSSION

Temperature dependences of the thermopower, for selected concentrations of  $\text{FeCl}_4^-$  are shown in Fig. 1. Similarly as in the case of other systems it can be observed that, for  $y > 0.002$ ,  $S$  increases with temperature suggesting metallic properties.

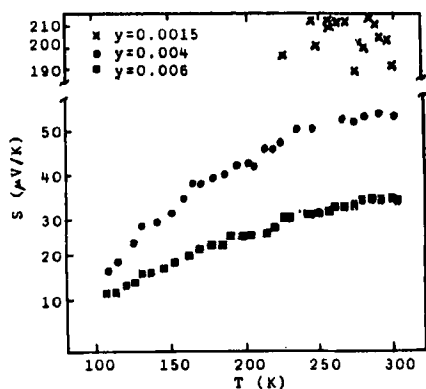


FIGURE 1 Temperature dependence of thermopower at ambient pressure for  $[\text{CH}(\text{FeCl}_4)_y]_x$   
(x)  $y = 0.001$ ,  
(•)  $y = 0.004$ ,  
(■)  $y = 0.006$

In the dopand concentration range studied the conductivity strongly increases with the increase of  $\text{FeCl}_4^-$  concentration and for a given concentration increases with the increase of the applied pressure. The maximum influence of the pressure is observed for the sample with lowest concentration, i.e.  $y = 0.002$  (see Table I).

If the temperature dependence of conductivity is assumed to obey the general formula  $\sigma = AT^{-1/2} \exp(-B/T^m)$ , from the least square fit of the experimental data the power coefficient  $m$  can be determined. In the case of  $y = 0.0048$ ,  $m$  adopts the following values:  $m = 0.26$ , for  $p = 1$  bar and  $m = 0.18$ , for  $p = 8.5$  kbar. The obtained values suggest the variable range hopping mechanism (VRH). However, neither a quantitative nor a qualitative agreement with VRH model can be found since the localization length determined on its basis is  $0.1 \text{ \AA}$  and it predicts the decrease of the density of states by a factor of 13 when going from 1 bar to 8.5 kbar pressure.

TABLE I Conductivities of  $[\text{CH}(\text{FeCl}_4)_y]_x$  measured at 77 K and 300 K, at ambient pressure and 8.5 kbar ( $\Sigma(T) \equiv \sigma(8.5, T) / \sigma(0, T)$ )

y	T K	$\sigma(0, T)$ $\Omega^{-1} \text{ cm}^{-1}$	$\sigma(8.5, T)$ $\Omega^{-1} \text{ cm}^{-1}$	$\Sigma(T)$	$\frac{d}{dT}\Sigma(T)$
0.002	300	$2.14 \cdot 10^{-2}$	$4.1 \cdot 10^{-2}$	1.92	-0.0087
	77	$3.32 \cdot 10^{-4}$	$12.8 \cdot 10^{-4}$	3.85	
0.0048	300	$7.3 \cdot 10^{-1}$	$11.2 \cdot 10^{-1}$	1.53	-0.0061
	77	$7.4 \cdot 10^{-2}$	$2.13 \cdot 10^{-1}$	2.88	
0.0074	300	3.4	4.9	1.44	-0.0035
	77	1.06	2.34	2.21	

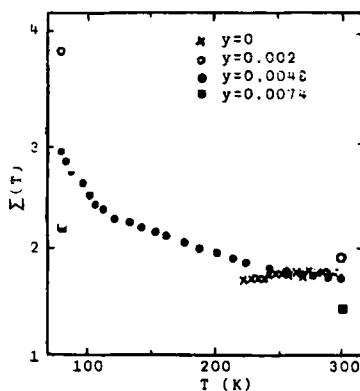


FIGURE 2 Ratio of the conductivity at 8.5 kbar and 1 bar vs: temperature for  $y = 0$  (x) (after<sup>7</sup>),  $y = 0.002$  (o),  $y = 0.0048$  (•) and  $y = 0.0074$  (■)

In Fig. 2 the temperature dependence of the ratio  $\Sigma(T) \equiv \sigma(p, T) / \sigma(0, T)$ , of undoped<sup>7</sup> and lightly doped  $(\text{CH})_x$  is shown.  $\Sigma$  decreases with temperature for the doped systems whereas it is almost constant ( $d\Sigma/dT = +0.0009$ ) in the undoped  $(\text{CH})_x$ . The behaviour of undoped  $(\text{CH})_x$  sample is thus properly described by the IHS model, but the results obtained for the doped samples are in strong disagreement with its predictions. Moreover, the average slope of  $\Sigma$  (i.e.  $d\Sigma/dT$ ) decreases with lowering of  $y$  (see Table I) and then suddenly jumps changing its sign (from -0.0087 for  $y = 0.002$  to +0.0009 for  $y = 0$ ).

CONCLUSIONS

The presented results of pressure and temperature dependence of conductivity for lightly doped polyacetylene ( $y \leq 0.0074$ ) are consistent neither with the variable range hopping model nor with the intersoliton hopping model.

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